NSN 5961-01-249-6932

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-249-6932 **Inclosure Material:** Glass or plastic **Overall Length:** Between 0.150 inches and 0.300 inches **Overall Diameter:** Between 0.115 inches and 0.155 inches **Mounting Method:** Terminal **Features Provided:** Mounting hardware **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 600.0 reverse voltage, instantaneous and 600.0 working peak reverse voltage, peak total value **Current Rating Per Characteristic:** 3.00 amperes forward current, average absolute and 80.00 amperes source cutoff current preset **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Special Features:** Item c/o 1n5190 as described, leads shaped and mounted to two; junction pattern arrangement: pn **Terminal Type And Quantity:** 2 uninsulated wire lead w/terminal lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** No